

Lead-free Green 2N7002V/VA DUAL N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

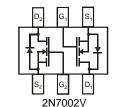
Features

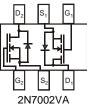
- Dual N-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- Lead Free By Design/RoHS Compliant (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 3 and 4)

Mechanical Data

- Case: SOT-563
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Alloy 42 or Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminals: Lead bearing terminal plating available. See Ordering Information Page 3, Note 8
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)

TOP VIEW





(KAS or ASK Marking Code)

(KAY or AYK Marking Code)

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units	
Drain-Source Voltage		V _{DSS}	60	V
Drain-Gate Voltage $R_{GS} \le 1.0 M\Omega$		V _{DGR}	60	V
Gate-Source Voltage	Continuous Pulsed	V _{GSS}	±20 ±40	V
Drain Current (Note 1)	Continuous	I _D	280	mA
Drain Current (Note 1)	Pulsed	I _{DM}	1.5	А

SOT-563

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Total Power Dissipation	PD	150	mW
Thermal Resistance, Junction to Ambient	$R_{ ext{ heta}JA}$	833	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added Lead.

3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

 Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

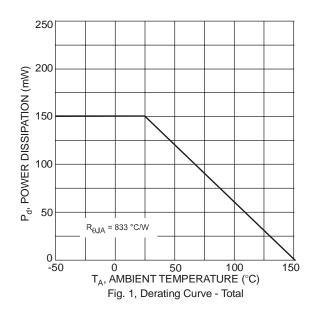


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)							
Drain-Source Breakdown Voltage		BV _{DSS}	60	70	_	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	@ T _C = 25°C @ T _C = 125°C	I _{DSS}	_	_	1.0 500	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Body Leakage		I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage		V _{GS(th)}	1.0		2.5	V	$V_{DS =} V_{GS,} I_D = 250 \mu A$
Static Drain-Source On-Resistance		R _{DS (ON)}			7.5 13.5	Ω	V _{GS} = 5V, I _D = 0.05A, V _{GS} = 10V, I _D = 0.5A, T _i = 125°C
On-State Drain Current		I _{D(ON)}	0.5	1.0	_	А	V _{GS} = 10V, V _{DS} = 7.5V
Forward Transconductance		g fs	80			mS	V _{DS} = 10V, I _D = 0.2A
DYNAMIC CHARACTERISTICS							
Input Capacitance		C _{iss}			50	pF	
Output Capacitance		Coss		_	25	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance		C _{rss}			5.0	pF	$V_{DS} = 23V, V_{GS} = 0V, T = 1.00012$
SWITCHING CHARACTERISTICS		·					·
Turn-On Delay Time		t _{D(ON)}	_	_	20	ns	$V_{DD} = 30V, I_D = 0.2A,$
Turn-Off Delay Time		t _{D(OFF)}			20	ns	$R_L = 150\Omega$, $V_{GEN} = 10V$, $R_{GEN} = 25\Omega$

Notes:

5. Short duration pulse test used to minimize self-heating effect.





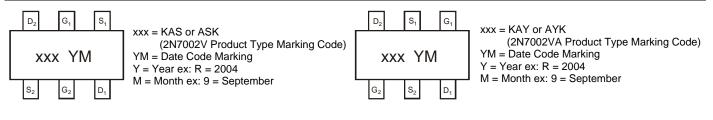
Ordering Information (Notes 6 and 7)

Part Number	Case	Packaging
2N7002V-7	SOT-563	3000/Tape & Reel
2N7002VA-7	SOT-563	3000/Tape & Reel
2N7002V-7-L	SOT-563	3000/Tape & Reel
2N7002VA-7-L	SOT-563	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

7. "-L" suffix on part number indicates Pb/Sn terminal plating. "-L" version is a Non Lead-Free, Non RoHS-compliant device.

Marking Information (Note 8)

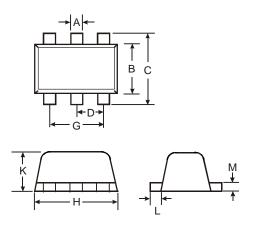


Notes: 8. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).

Date Code Key

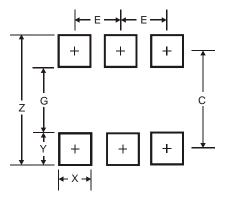
Year	2004	20	05	2006	2007	20	08	2009	2010	20	11	2012
Code	R	5	6	Т	U	١	/	W	Х	Ň	(Z
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Package Outline Dimensions



	SOT-563						
Dim	Min	Min Max Ty					
Α	0.15	0.30	0.20				
В	1.10	1.25	1.20				
С	1.55	1.55 1.70 1.60					
D	0.50						
G	0.90	1.10	1.00				
н	1.50	1.70	1.60				
κ	0.55	0.60	0.60				
L	0.10	0.30	0.20				
М	0.10	0.18	0.11				
All	Dimens	ions in I	mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
С	1.7
E	0.5



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